DOT MATRIX DIGIT LED DISPLAY (0.7Inch)

LMD5702BEGR/R1-XX

DATA SHEET

DOC. NO : QW0905-LMD5702BEGR/R1-XX

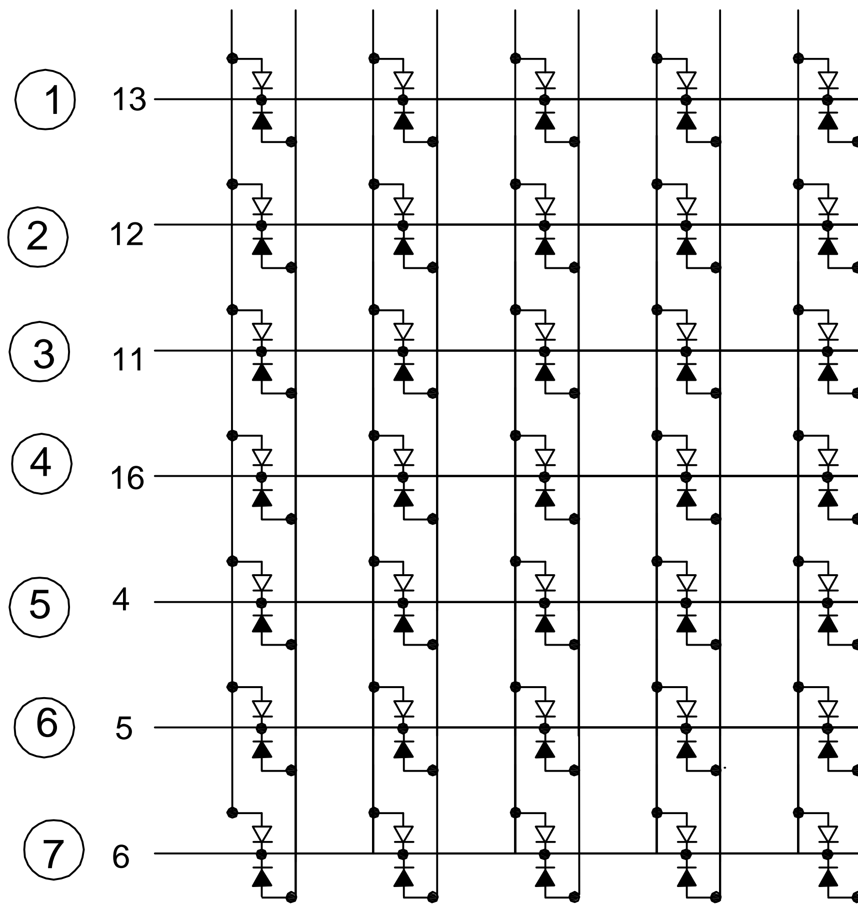
REV. : A

DATE : 08 - Feb. - 2006

Package Dimensions

Note : 1.All dimension are in millimeters and (Inch) tolerance is ±0.25mm unless otherwise noted.
2.Specifications are subject to change without notice.

Internal Circuit Diagram



Electrical Connection

PIN NO.	LMD5702BEGR/R1-XX	PIN NO.	LMD5702BEGR/R1-XX
1	Anode Column 2 (Green)	10	Anode Column 5 (Red)
2	Anode Column 1 (Red)	11	Cathode Row 3
3	Anode Column 1 (Green)	12	Cathode Row 2
4	Cathode Row 5	13	Cathode Row 1
5	Cathode Row 6	14	Anode Column 3 (Green)
6	Cathode Row 7	15	Anode Column 2 (Red)
7	Anode Column 4 (Green)	16	Cathode Row 4
8	Anode Column 5 (Green)	17	Anode Column 3 (Red)
9	Anode Column 4 (Red)		

Absolute Maximum Ratings at Ta=25 ℃

Parameter	Symbol	Ratings		UNIT
		E	G	
Forward Current Per Chip	I_F	30	30	mA
Peak Forward Current Per Chip (Duty 1/10,0.1ms Pulse Width)	I_{FP}	120	120	mA
Power Dissipation Per Chip	PD	100	100	mW
Reverse Current Per Any Chip	Ir	10		μA
Operating Temperature	T_{opr}	-25 ~ +85		℃
Storage Temperature	Tstg	-25 ~ +85		℃
Solder Temperature 1/16 Inch Below Seating Plane For 3 Seconds At 260 ℃				

Part Selection And Application Information(Ratings at 25℃)

PART NO	CHIP		common cathode or anode	λP (nm)	△λ (nm)	Electrical					IV-M
						Vf(v)			Iv(mcd)		
	Material	Emitted				Min.	Typ.	Max.	Min.	Typ.	
LMD5702BEGR/R1-XX	GaAsP/GaP	Orange	Common Anode	640	45	1.7	2.1	2.6	3.05	5.0	2:1
	GaP	Green		565	30	1.7	2.1	2.6	5.0	8.5	

Note : 1.The forward voltage data did not including ±0.1V testing tolerance.
2. The luminous intensity data did not including ±15% testing tolerance.

Test Condition For Each Parameter

Parameter	Symbol	Unit	Test Condition
Forward Voltage Per Chip	Vf	volt	If=20mA
Luminous Intensity Per Chip	Iv	mcd	If=10mA
Peak Wavelength	λp	nm	If=20mA
Spectral Line Half-Width	△λ	nm	If=20mA
Reverse Current Any Chip	Ir	μA	Vr=5V
Luminous Intensity Matching Ratio	IV-M		

Typical Electro-Optical Characteristics Curve

E CHIP

Fig.1 Forward current vs. Forward Voltage

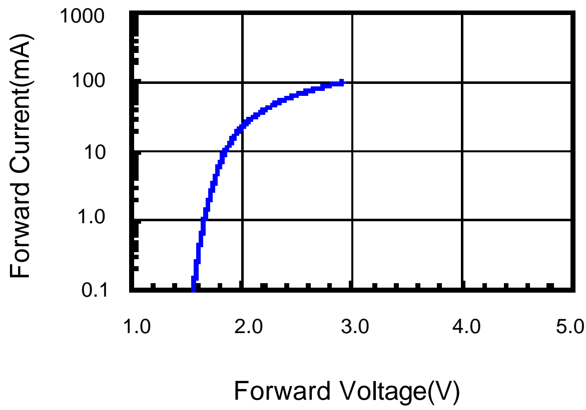


Fig.2 Relative Intensity vs. Forward Current

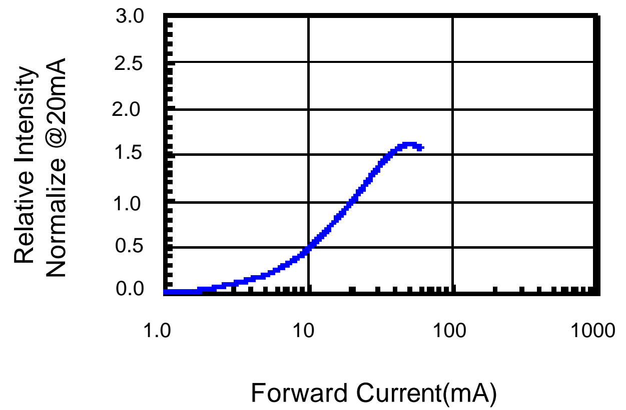


Fig.3 Forward Voltage vs. Temperature

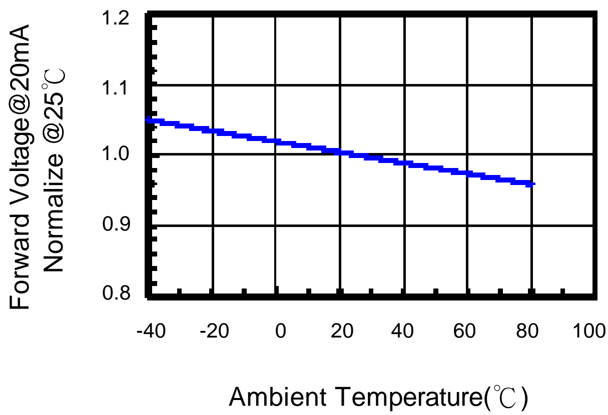


Fig.4 Relative Intensity vs. Temperature

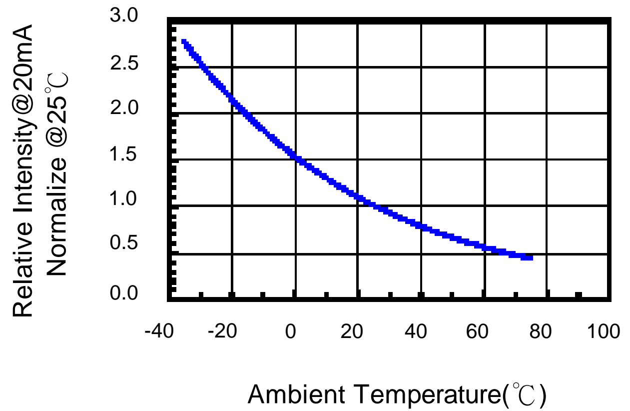
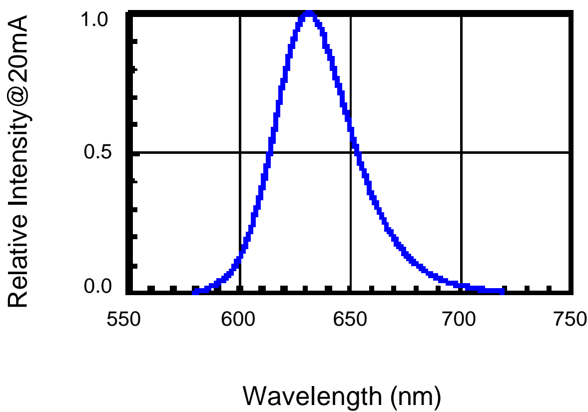


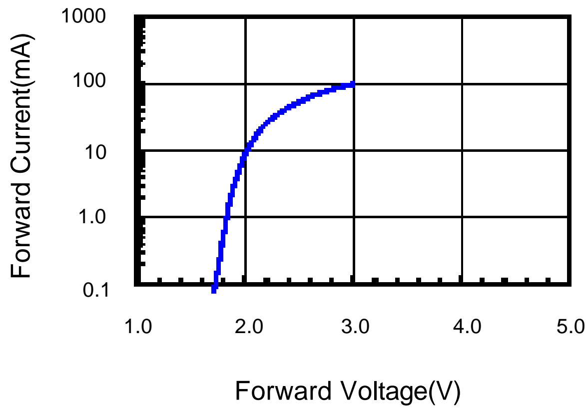
Fig.5 Relative Intensity vs. Wavelength



Typical Electro-Optical Characteristics Curve

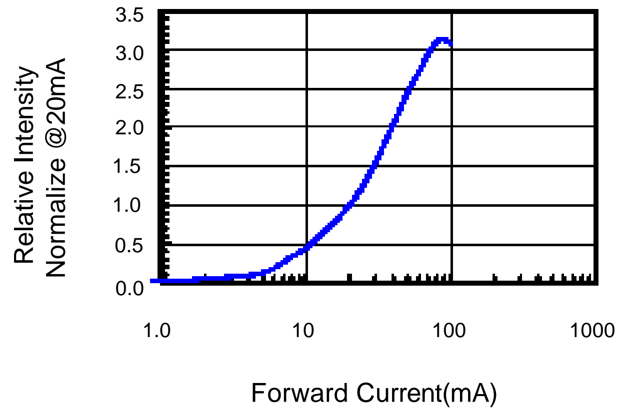
G CHIP

Fig.1 Forward current vs. Forward Voltage



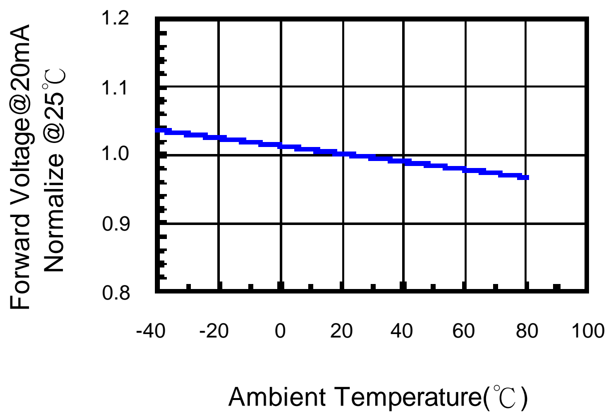
Forward Voltage(V)

Fig.2 Relative Intensity vs. Forward Current



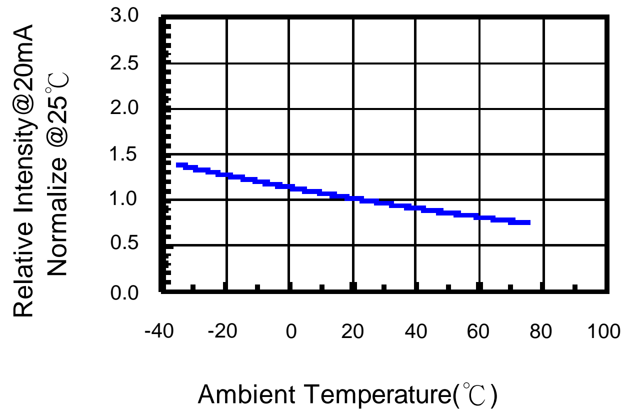
Forward Current(mA)

Fig.3 Forward Voltage vs. Temperature



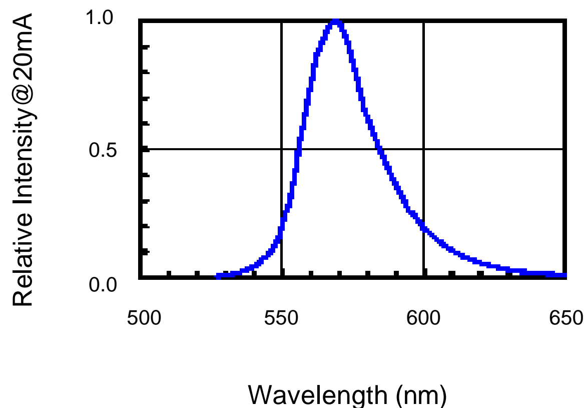
Ambient Temperature(℃)

Fig.4 Relative Intensity vs. Temperature



Ambient Temperature(℃)

Fig.5 Relative Intensity vs. Wavelength



Wavelength (nm)

Reliability Test:

Test Item	Test Condition	Description	Reference Standard
Operating Life Test	1.Under Room Temperature 2.If=10mA 3.t=1000 hrs (-24hrs, +72hrs)	This test is conducted for the purpose of detemining the resistance of a part in electrical and themal stressed.	MIL-STD-750: 1026 MIL-STD-883: 1005 JIS C 7021: B-1
High Temperature Storage Test	1.Ta=105 ℃±5℃ 2.t=1000 hrs (-24hrs, +72hrs)	The purpose of this is the resistance of the device which is laid under condition of high temperature for hours.	MIL-STD-883:1008 JIS C 7021: B-10
Low Temperature Storage Test	1.Ta=-40 ℃±5℃ 2.t=1000 hrs (-24hrs, +72hrs)	The purpose of this is the resistance of the device which is laid under condition of low temperature for hours.	JIS C 7021: B-12
High Temperature High Humidity Test	1.Ta=65 ℃±5℃ 2.RH=90 %~95% 3.t=240hrs ±2hrs	The purpose of this test is the resistance of the device under tropical for hours.	MIL-STD-202:103B JIS C 7021: B-11
Thermal Shock Test	1.Ta=105 ℃±5℃ &-40℃±5℃ (10min) (10min) 2.total 10 cycles	The purpose of this is the resistance of the device to sudden extreme changes in high and low temperature.	MIL-STD-202: 107D MIL-STD-750: 1051 MIL-STD-883: 1011
Solder Resistance Test	1.T.Sol=260 ℃±5℃ 2.Dwell time= 10 ±1sec.	This test intended to determine the thermal characteristic resistance of the device to sudden exposures at extreme changes in temperature when soldering the lead wire.	MIL-STD-202: 210A MIL-STD-750: 2031 JIS C 7021: A-1
Solderability Test	1.T.Sol=230 ℃±5℃ 2.Dwell time=5 ±1sec	This test intended to see soldering well performed or not.	MIL-STD-202: 208D MIL-STD-750: 2026 MIL-STD-883: 2003 JIS C 7021: A-2